100kHz, 670nA, Non-Unity Gain, Rail-to-Rail I/O CMOS Operational Amplifier

1 FEATURES

- **GAIN BANDWIDTH:100kHz**
- **RAIL-TO-RAIL INPUT AND OUTPUT ±1mV Typical Vos**
- **INPUT VOLTAGE RANGE: -0.1V to +5.6V with Vs = 5.5V**
- **SUPPLY RANGE: +1.4V to +5.5V**
- **STABLE FOR GAINS ≥ 10**
- **SPECIFIED UP TO +125°C**
- **Micro SIZE PACKAGES: SOIC8**

2 APPLICATIONS

- **SENSORS**
- **PHOTODIODE AMPLIFICATION**
- **WEARABLE PRODUCTS**
- **TEMPERATURE MEASUREMENT**
- **BATTERY POWERED SYSTEM**

3 DESCRIPTIONS

The RES2394IDR families of products offer low voltage operation and rail-to-rail input and output, as well as excellent speed/power consumption ratio, providing an excellent bandwidth (100kHz) and slew rate of 30V/ms. The op-amps are stable for gains ≥ 10 and feature an ultra-low input bias current.

The devices are ideal for sensor interfaces, active filters and portable applications. The RES2394IDR families of operational amplifiers are specified at the full temperature range of −40°C to +125°C under single or dual power supplies of 1.4V to 5.5V.

Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE(NOM)
RES2394IDR		
	SOIC8	4.90mm×3.90mm

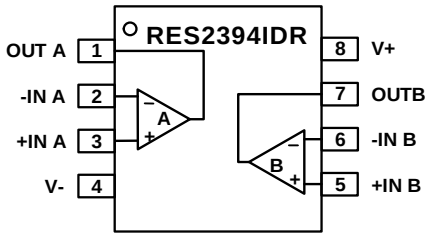
(1) For all available packages, see the orderable addendum at the end of the data sheet.

5 PACKAGE/ORDERING INFORMATION (1)

Orderable Device	Package Type	Pin	Channel	Op Temp(°C)	Device Marking (2)	Package Qty
RES2394IDR	SOIC8	8	2	-40°C ~125°C	RES2394IDR	Tape and Reel,4000

NOTE:
(1) This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.
(2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.

6 Pin Configuration and Functions (Top View)



SOIC8

Pin Description

NAME	RES2394IDR	I/O (1)	DESCRIPTION
	SOIC8		
-INA	2	I	Inverting input, channel A
+INA	3	I	Noninverting input, channel A
-INB	6	I	Inverting input, channel B
+INB	5	I	Noninverting input, channel B
OUTA	1	O	Output, channel A
OUTB	7	O	Output, channel B
V-	4	-	Negative (lowest) power supply
V+	8	-	Positive (highest) power supply
-	Thermal Pad	-	Connect thermal pad to V-

(1) I = Input, O = Output.

7 SPECIFICATIONS

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
Voltage	Supply, V_S=(V+) - (V-)			7	V
	Signal input pin (2)		(V-)-0.5	(V+) +0.5	
	Signal output pin (3)		(V-)-0.5	(V+) +0.5	
Current	Signal input pin (2)		-10	10	mA
	Signal output pin (3)		-55	55	mA
	Output short-circuit (4)		Continuous		
θ_{JA}	Package thermal impedance (5)				°C/W
		SOIC8		110.88	
Temperature	Operating range, T_A		-40	125	°C
	Junction, T_J (6)		-40	150	
	Storage, T_{stg}		-65	150	

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
(2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less.
(3) Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.5V beyond the supply rails should be current-limited to ±55mA or less.
(4) Short-circuit to ground, one amplifier per package.
(5) The package thermal impedance is calculated in accordance with JESD-51.
(6) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.

7.2 ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±5000	V
		Machine Model (MM)	±400	

(1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.

ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Supply voltage，V_S= (V+) - (V-)	Single-supply	1.4		5.5	V
	Dual-supply	±0.7		±2.75	

7.4 ELECTRICAL CHARACTERISTICS

(At T_A=+25°C, V_S=5.0V, R_L=1MΩ connected to V_S/2, and V_{OUT}=V_S/2, Full [9] = -40°C to +125°C, unless otherwise noted.) [1]

PARAMETER		CONDITIONS	T_J	RES2394IDR			
				MIN[2]	TYP[3]	MAX[2]	UINT
POWER SUPPLY							
V_S	Operating Voltage Range		25°C	1.4		5.5	V
I_Q	Quiescent Current/Amplifier		25°C		670	1500	nA
PSRR	Power-Supply Rejection Ratio	V_S=1.4V to 5.5V, V_{CM}=(V-)+0.5V	25°C	60	70		dB
INPUT							
V_{OS}	Input Offset Voltage	V_{CM} =V_S/2	25°C	-5	±1	5	mV
V_{OS} T_C	Input Offset Voltage Average Drift	V_{CM} =V_S/2	Full		±2.3		uV/°C
IB	Input Bias Current [4] [5]		25°C		±1	±10	pA
I_{OS}	Input Offset Current [4]		25°C		±1	±10	pA
V_{CM}	Common-Mode Voltage Range	V_S= 5.5V	25°C	-0.1		5.6	V
CMRR	Common-Mode Rejection Ratio	V_S= 5.5V, V_{CM}=-0.1V to 4V	25°C	63	75		dB
		V_S= 5.5V, V_{CM}=-0.1V to 5.6V	25°C	58	70		dB
OUTPUT							
A_{OL}	Open-Loop Voltage Gain	V_S=1.4V, R_L=50KΩ, V_O=V_S-0.1V	25°C	62	80		dB
		V_S=5.0V, R_L=50kΩ, V_O=V_S-0.1V	25°C	65	85		dB
	Output Swing From Rail	R_L=50KΩ	25°C		5		mV
I_{OUT}	Output Short-Circuit Current [6] [7]		25°C		±30		mA
FREQUENCY RESPONSE							
SR	Slew Rate [8]		25°C		30		V/ms
GBP	Gain-Bandwidth Product		25°C		100		kHz
PM	Phase Margin		25°C		60		°
NOISE							
e_np-p	Input Voltage Noise	f = 0.1 Hz to 10 Hz	25°C		2.4		uVpp
e_n	Input Voltage Noise Density	f = 1 kHz	25°C		160		nV/$\sqrt{\text{Hz}}$

NOTE:

(1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.

(2) Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.

(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.

(4) This parameter is ensured by design and/or characterization and is not tested in production.

(5) Positive current corresponds to current flowing into the device.

(6) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A. The maximum allowable power dissipation at any ambient temperature is PD = ($T_{J(MAX)}$ - T_A) / $R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.

(7) Short circuit test is a momentary test.

(8) Number specified is the slower of positive and negative slew rates.

(9) Specified by characterization only.

7.5 TYPICAL CHARACTERISTICS

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, V_S=5V, R_L = 1MΩ connected to V_S/2, C_L=60pF V_{CM} = V_S/2, unless otherwise noted.

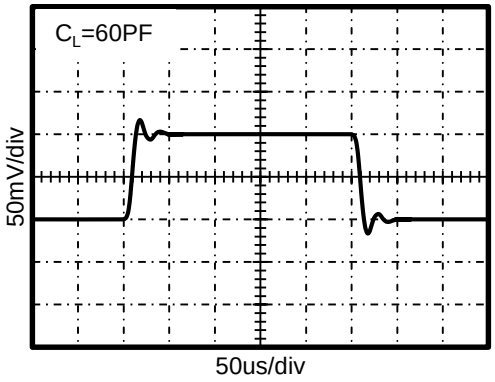


Figure 1. Small-Signal Step Response

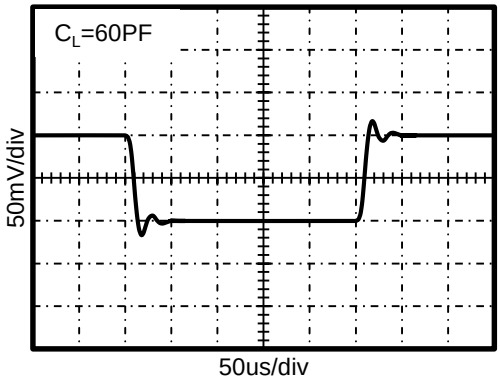


Figure 2. Small-Signal Step Response

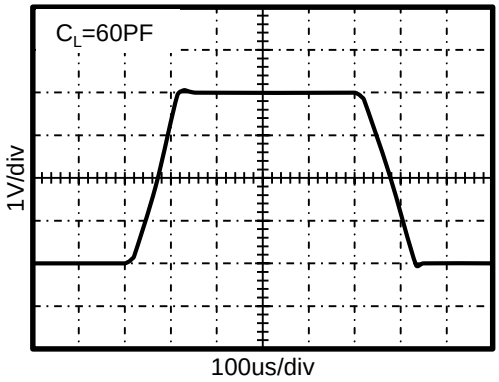


Figure 3. Large-Signal Step Response

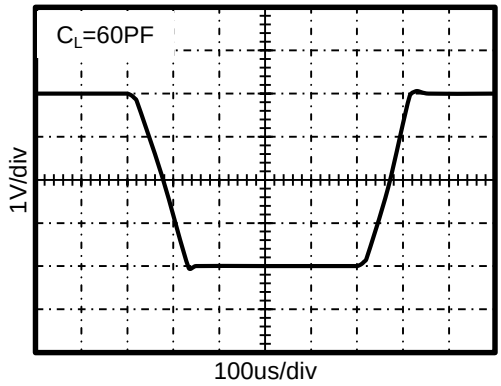


Figure 4. Large-Signal Step Response

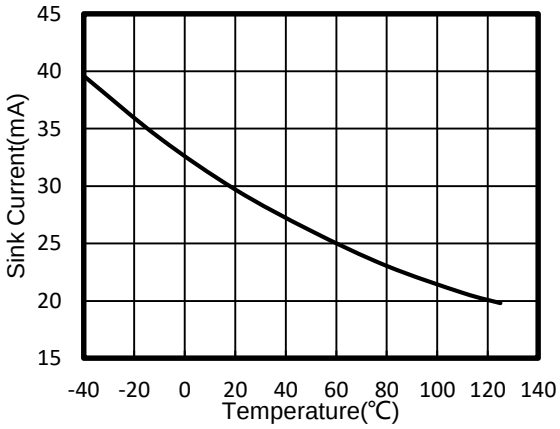


Figure 5. Sink Current vs Temperature

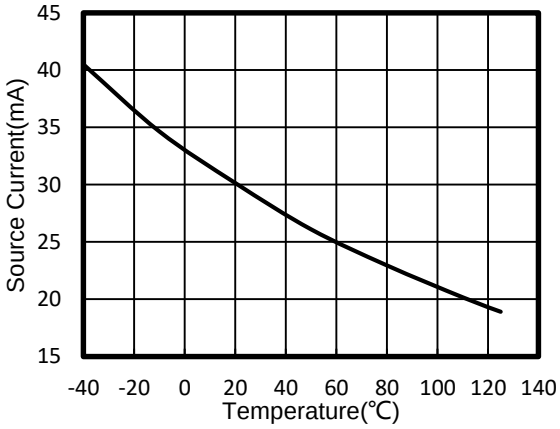
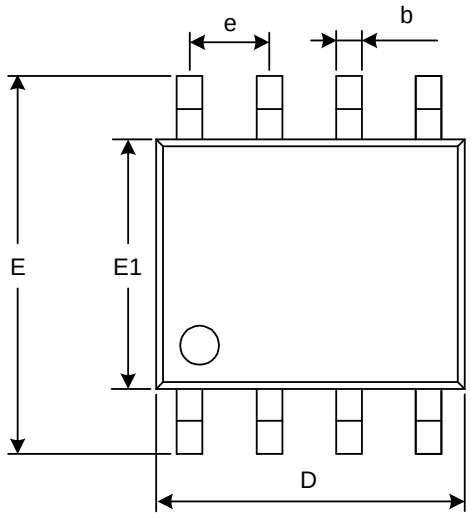
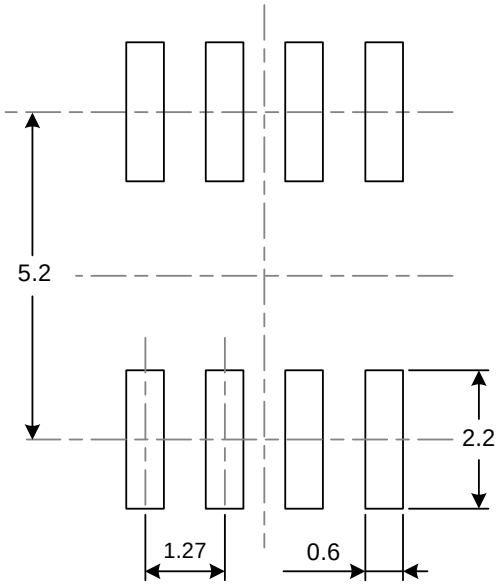


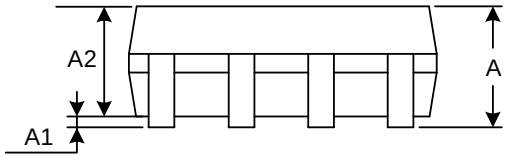
Figure 6. Source Current vs Temperature

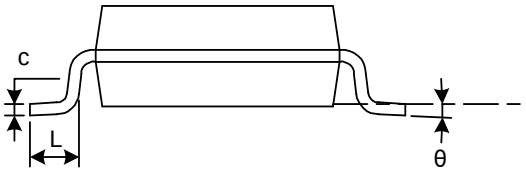
SOIC8





RECOMMENDED LAND PATTERN (Unit: mm)



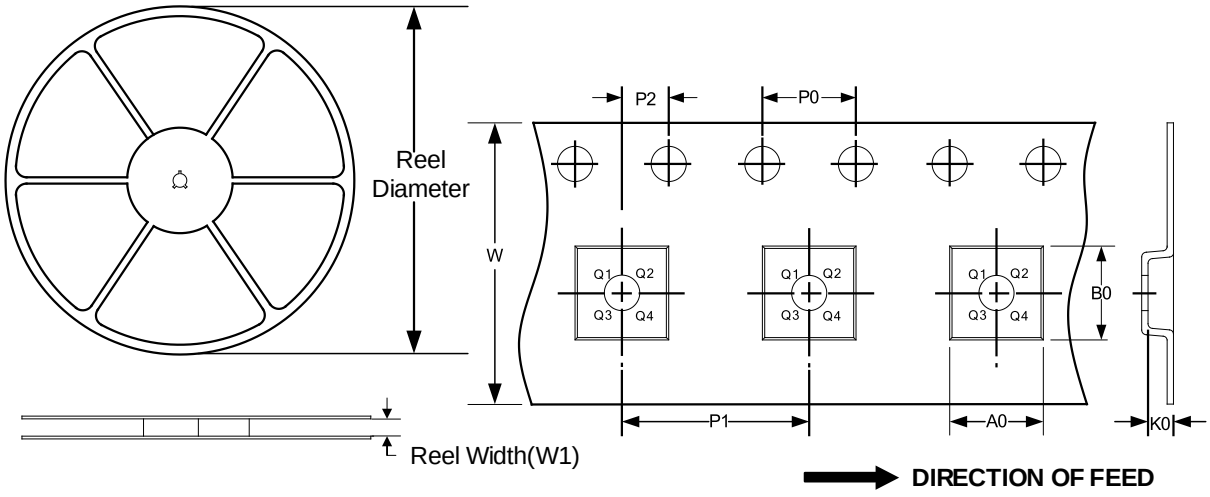


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270(BSC)		0.050(BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

9 TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC8	13''	12.4	6.40	5.40	2.10	4.0	8.0	2.0	8.0	Q2

NOTE:
1. All dimensions are nominal.
2. Plastic or metal protrusions of 0.15mm maximum per side are not included.